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> USB 3.0 TRANSMEMORY™ - U363

A USB WITH A FEELING OF QUALITY

Worry less about leaving it behind. Attach it easily to your house or car keys. Functionality is balanced with sleek design & a read speed of 120MB/s. The new TransMemory USB 3.0 is housed in a high quality projecting metal body and is available in three different capacities: 32GB, 64GB, and 128GB.



> SPECIFICATIONS

TransMemory™ U363 - USB 3.0 Flash Drives

Overview:

Capacity	32GB, 64GB, 128GB ¹
Interface	USB3.0 Super Speed* and USB2.0 Hi-Speed ²
Power Supply	Bus powered from USB port.
Transfer Speed	Max. Read: 120MB/s ³
Warranty	5 Years

Physical Specification:

Dimensions	39 mm (L) × 12,2 mm (W) × 4,5 mm (H)
Weight	Approx. 6 g
Compatible PC	Models equipped with the following OS, and the Type-A USB interface as a standard feature • OS X v10.6.6 - v10.11 • macOS X v10.12 • Windows 7 • Windows 8.1 • Windows 10

Environment:

Operating Temp.	0° to +40°C (Recommended)
Storage Temp.	-20° to +60°C (Recommended)

	32GB	64GB	128GB
Model Numbers:			
EAN Code	4047999400301	4047999400318	4047999400325
Blister Part Number	THN-U363S0320E4	THN-U363S0640E4	THN-U363S1280E4
Part Number with Suffix	THN-U363S0320E4(TU)	THN-U363S0640E4(TU)	THN-U363S1280E4(TU)
Blister Dimensions	76mm (W) x 127mm (L)		
MOQ	20 pcs		

> **TOSHIBA – THE INVENTOR OF FLASH MEMORY**

In 1984, Toshiba developed a new type of semiconductor memory called flash memory, leading the industry into the next generation ahead of its competitors.

Some time later in 1987, NAND flash memory was developed, and this has since been used in a variety of memory cards and electronic equipment. The NAND flash market has grown rapidly, with flash memory becoming an internationally standardized memory device. Toshiba, the inventor of flash memory, has carved out a path to a new era in which we are all able to carry videos, music and data with us wherever we go.

History of Flash Memory	
1984	Developed NOR-type Flash Memory
1987	Developed NAND-type Flash Memory
Jul. 2000	Released SD™ Memory Card
Jun. 2003	Released miniSD™ Memory Card
Dec. 2003	Released USB Flash Memory
Jul. 2006	Released microSD™ Memory Card
Oct. 2006	Released SDHC™ Memory Card
May. 2010	Released SDXC™ Memory Card
Sep. 2010	Developed SDHC Memory Card – World's fastest*4
Sep. 2011	Developed World's first SDHC Memory Card with Embedded Wireless LAN, FlashAir™
Mar. 2012	Released the new brand EXCERIA™
Jul. 2013	Developed EXCERIA™ UHS II World's fastest Write Speed
Feb. 2015	Developed World's first SD Card with built-in NFC
Sep. 2015	Developed World's first SDHC Memory Card with Embedded TransferJet™ - Technology
Mar. 2016	Developed EXCERIA™ microSD UHS-II World's fastest Write Speed*4



*1 Capacity is based on installed flash memory and not user available memory as part of the memory is used for management functions. User available memory capacity are as listed above (1GB = 1,073,741,824 bytes).

*2 The terms 'Hi-Speed USB 2.0' and 'SuperSpeed USB 3.0' used herein are the names of specifications upon which this product is based; they do not warrant the speed of its operation.

*3 1MB/s is calculated as 1,000,000 bytes/s. The value is the best value obtained in specific test environment at Toshiba Memory Corporation and Toshiba Memory Corporation does not warrant read speed use in individual devices. Read speed may vary depending on user specifications such as devices used and file size read.

*4 At the date of release

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